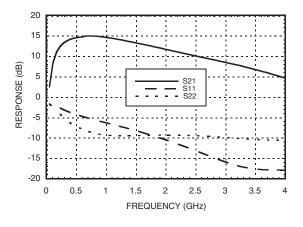


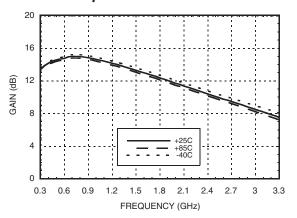


SMT PHEMT LOW NOISE AMPLIFIER, 0.3 - 3.0 GHz

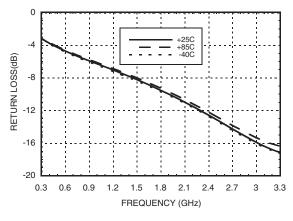
Broadband Gain & Return Loss



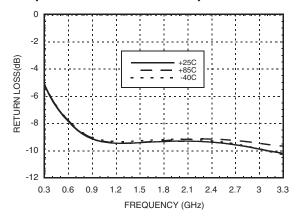
Gain vs. Temperature



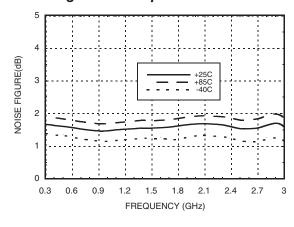
Input Return Loss vs. Temperature



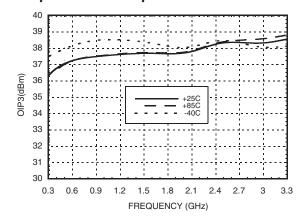
Output Return Loss vs. Temperature



Noise Figure vs. Temperature



Output IP3 vs. Temperature



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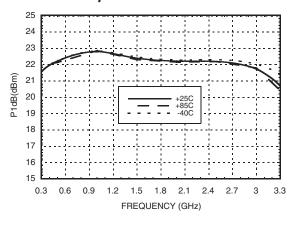
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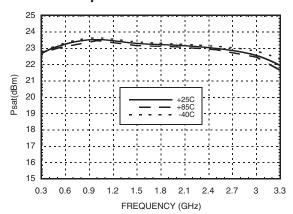


SMT PHEMT LOW NOISE AMPLIFIER, 0.3 - 3.0 GHz

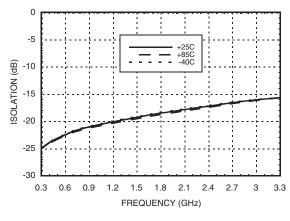
P1dB vs. Temperature



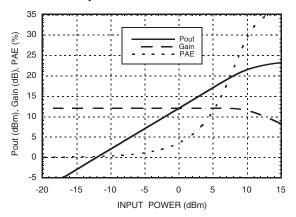
Psat vs. Temperature



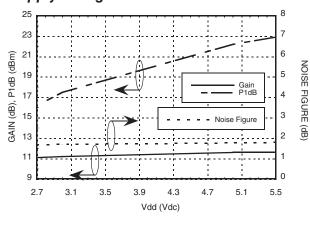
Reverse Isolation vs. Temperature



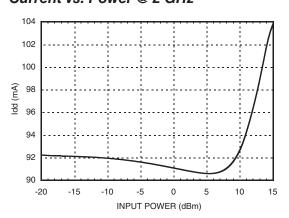
Power Compression @ 2 GHz



Gain, Noise Figure & Power vs. Supply Voltage @ 2 GHz



Current vs. Power @ 2 GHz



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SMT PHEMT LOW NOISE AMPLIFIER, 0.3 - 3.0 GHz

Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+7.0 Vdc
RF Input Power (RFIN)(Vdd = +5.0 Vdc)	15 dBm
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 7.5 mW/°C above 85 °C)	0.488 W
Thermal Resistance (channel to lead)	133 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

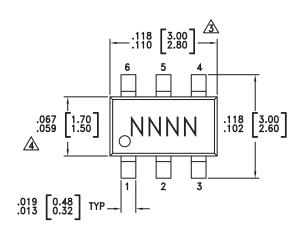
Typical Supply Current vs. Vdd

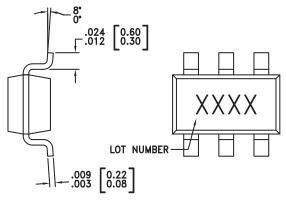
Vdd (V)	ldd (mA)
2.7	89
3.0	89
5.0	90
5.5	90



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

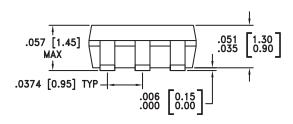
Outline Drawing





NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 5. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC374	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H374 XXXX
HMC374E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	374E XXXX

- [1] Max peak reflow temperature of 235 $^{\circ}\text{C}$
- [2] Max peak reflow temperature of 260 $^{\circ}\text{C}$
- [3] 4-Digit lot number XXXX

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SMT PHEMT LOW NOISE AMPLIFIER, 0.3 - 3.0 GHz

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1,4	N/C	These pins may be connected to RF/DC ground. Performance will not be affected.	
2, 5	GND	These pins must be connected to RF/DC ground.	GND
3	IN	This pin is DC coupled. An off-chip DC blocking capacitor is required.	IN OUT
6	OUT	RF output and DC Bias for the output stage. See application circuit for off-chip components.	

Application Circuit

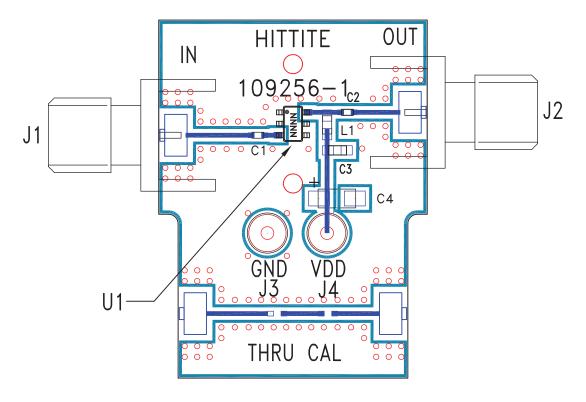
Recommen	ided Component Values						
C1, C2	150 pF						
C3	1,000 pF				♀∨	dd	
C4	4.7 μF				'		
L1	27 nH					C4	
	RFIN O	C1 	JN JN	HMC374	L1 3	RFOU' C2	Т





SMT PHEMT LOW NOISE AMPLIFIER, 0.3 - 3.0 GHz

Evaluation PCB



List of Materials for Evaluation PCB 109258 [1]

Item	Description
J1, J2	PCB Mount SMA Connector
J3, J4	DC Pin
C1, C2	150 pF Capacitor, 0402 Pkg.
C3	1000 pF Capacitor, 0603 Pkg.
C4	4.7 Capacitor, Tantalum
L1	27 nH Inductor, 0603 Pkg.
U1	HMC374 / HMC374E Amplifier
PCB [2]	109256 Evaluation PCB

^[1] Reference this number when ordering complete evaluation PCB $\,$

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown above. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

^[2] Circuit Board Material: Roger 4350